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<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> (use as many sheets as necessary)		Application Number	09/918,115
		Filing Date	July 30, 2001
		First Named Inventor	Graetzel et al.
		Group Art Unit	2811
		Examiner Name	
Sheet 1 of 2	Attorney Docket Number	16090-23	

U.S. PATENT DOCUMENTS						
Examiner Initials*	Cite No. <sup>1</sup>	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code <sup>2</sup> (if known)			

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		Office <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)				
SL			DE 19711713 A1		Hoechst AG	10-01-1998		

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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Sheet 2 of 2

Compleat if Known

Application Number	09/918,115
Filing Date	July 30, 2001
First Named Inventor	Graetzel et al.
Group Art Unit	2811
Examiner Name	
Attorney Docket Number	16090-23

### OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
SP		VOGEL et al. <u>Sensitization of highly porous, polycrystalline TiO<sub>2</sub> electrodes by quantum sized CdS</u> , Chemical Physics Letters, Nov. 9, 1990, pp. 241-246, Vol.174, No.3,4, Elsevier Science	
SP		O'REGAN et al. <u>A low-cost, high-efficiency solar cell based on dye-sensitized colloidal TiO<sub>2</sub> films</u> , Letters to Nature, Oct. 24, 1991, Vol. 353.	
SP		VOGEL et al. <u>Quantum-Sized PbS, CdS, Ag<sub>2</sub>S, Sb<sub>2</sub>S<sub>3</sub>, and Bi<sub>2</sub>S<sub>3</sub> Particles as Sensitizers for Various Nanoporous Wide-Bandgap Semiconductors</u> , J. Phys. Chem., 1994, pp. 3183-2188, Vol. 98.	
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SP		Siebentritt et al. <u>CdTe and CdS as Extremely Thin Absorber Materials in an ETA solar cell</u> , 14th European Photovoltaic Solar Energy Conference, June 30, 1997, pp. 1823-1826, Barcelona, SP	
SP		Salafsky et al. <u>Photoinduced charge separation and recombination in a conjugated polymer-semiconductor nanocrystal composite</u> , Chemical Physics Letters, July 3, 1998, pp.297-303, Vol.290, No.4/06	
SP		Rost et al. <u>Transparent P-Type Semiconductors for the eta Solar Cell ...</u> , 2nd Wrld. Conf. and Exh. on Photovoltaic Solar Energy Conversion, July 6-10, 1998, pp.212-215, Vienna, Austria.	
SP		Bach et al. <u>Solid-state dye-sensitized mesoporous TiO<sub>2</sub> solar cells ...</u> , Letters to Nature, Oct. 8, 1998, pp. 583-585, Vol 395, MacMillan Journals Ltd., London.	
SP		Moller et al. <u>A novel disposition technique for compound semiconductors on highly porous substrates: ILGAR</u> , Thin Solid Films, Feb. 21, 2000, pp.113-117, Vol.361/362, Elsevier-Sequoia	
SP		Bach, U., <u>Solid-State Dye-Sensitized Mesoporous TiO<sub>2</sub> Solar Cells</u> , Thesis presented to Ecole Polytechnique Federale de Lausanne, 2000, Lausanne, Switzerland.	

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